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FDD8878 / FDU8878 N-Channel PowerTrench[®] MOSFET **30V, 40A, 15m**Ω

Features

- $r_{DS(ON)} = 15m\Omega$, $V_{GS} = 10V$, $I_D = 35A$
- r_{DS(ON)} = 18.5mΩ, V_{GS} = 4.5V, I_D = 35A
- High performance trench technology for extremely low r_{DS(ON)}
- Low gate charge
- High power and current handling capability
- RoHS Compliant



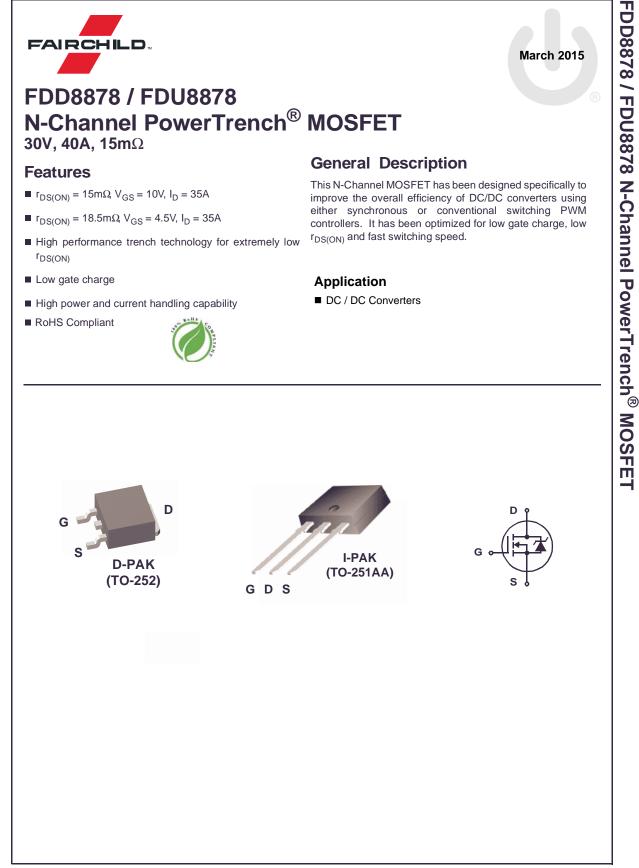
General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{\text{DS}(\text{ON})}$ and fast switching speed.

March 2015

Application

DC / DC Converters



Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	30	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current		
	Continuous ($T_c = 25^{\circ}C$, $V_{GS} = 10V$) (Note 1)	40	A
I _D	Continuous ($T_C = 25^{\circ}C$, $V_{GS} = 4.5V$) (Note 1)	36	A
-	Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, with $R_{\theta JA} = 52^{\circ}C/W$)	11	A
	Pulsed	Figure 4	A
E _{AS}	Single Pulse Avalanche Energy (Note 2)	25	mJ
D	Power dissipation	40	W
D	Derate above 25°C	0.27	W/ºC
Γ _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C

Thermal Characteristics

R_{\thetaJC}	Thermal Resistance Junction to Case TO-252, TO-251	3.75	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient TO-252, TO-251	100	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient TO-252, 1in ² copper pad area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8878	FDD8878	TO-252AA	13"	16mm	2500 units
FDU8878	FDU8878	TO-251AA	Tube	N/A	75 units

Electrical Characteristics $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test C	onditions	Min	Тур	Max	Units
Off Char	acteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V ₀	30	-	-	V	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24V$		-	-	1	A
		$V_{GS} = 0V$	$T_{\rm C} = 150^{\rm o}{\rm C}$	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V		-	-	±100	nA

On Characteristics

V _{GS(TH)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	1.2	-	2.5	V
	Drain to Source On Resistance	I _D = 35A, V _{GS} = 10V	-	0.011	0.015	
r		$I_{D} = 35A, V_{GS} = 4.5V$	-	0.014	0.0185	0
r _{DS(ON)}		$I_D = 35A, V_{GS} = 10V,$ $T_J = 175^{\circ}C$	-	0.018	0.024	

CISS	Input Capacitance				880	-	pF
C _{OSS}	Output Capacitance	$V_{DS} = 15V, V_{GS} = 15V$	$V_{DS} = 15V, V_{GS} = 0V,$			-	pF
C _{RSS}	Reverse Transfer Capacitance	1 - 1101112	-1 = 1101112		110	-	pF
R _G	Gate Resistance	V _{GS} = 0.5V, f = 1	MHz	-	3.1	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0V \text{ to } 10V$		-	19	26	nC
Q _{g(5)}	Total Gate Charge at 5V	$V_{GS} = 0V \text{ to } 5V$	$V_{GS} = 0V \text{ to } 5V$ $V_{GS} = 0V \text{ to } 1V$ $V_{DD} = 15V$ $I_D = 35A$ $I_g = 1.0\text{mA}$	-	10	14	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{rac} = 0V$ to $1V$		-	0.9	1.3	nC
Q _{gs}	Gate to Source Gate Charge			-	2.6	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		'g = 1.011A	-	1.7	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	4.5	-	nC

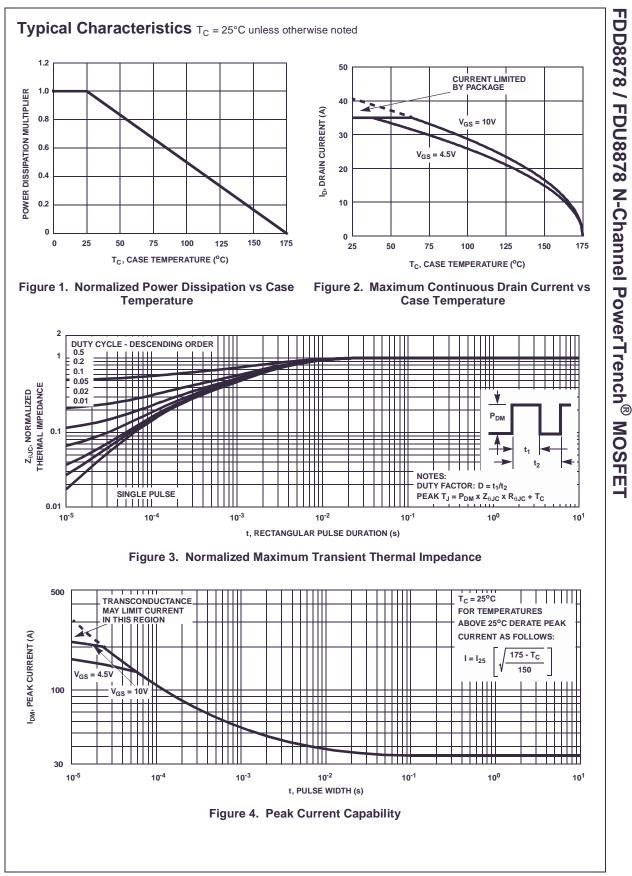
Switching Characteristics ($V_{GS} = 10V$)

t _{ON}	Turn-On Time		-	-	129	ns
t _{d(ON)}	Turn-On Delay Time		-	7	-	ns
t _r	Rise Time	$V_{DD} = 15V, I_D = 35A$ $V_{GS} = 4.5V, R_{GS} = 16\Omega$	-	79	-	ns
t _{d(OFF)}	Turn-Off Delay Time		-	38	-	ns
t _f	Fall Time		-	27	-	ns
t _{OFF}	Turn-Off Time		-	-	97	ns

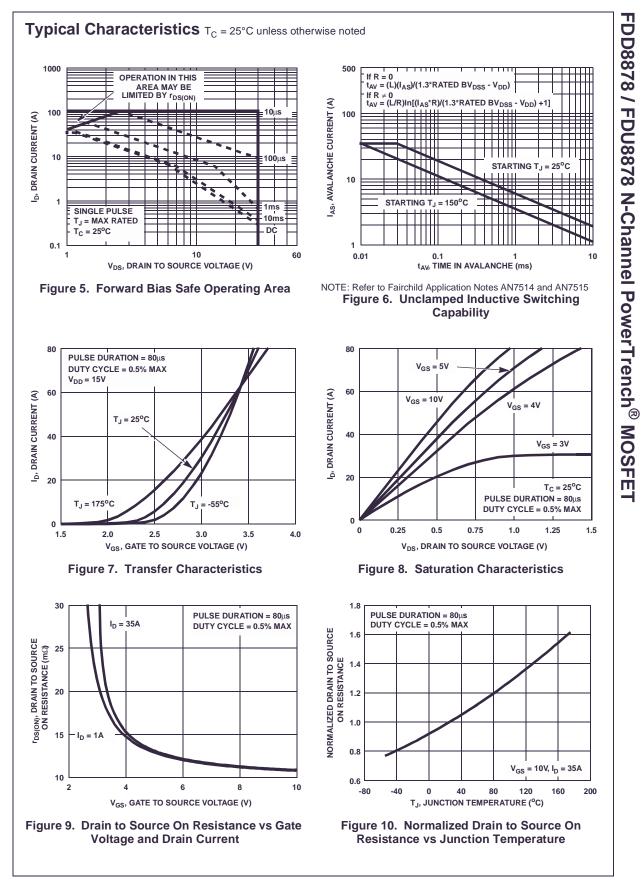
Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	I _{SD} = 35A	-	-	1.25	V
		I _{SD} = 3.2A	-	-	1.0	V
t _{rr}	Reverse Recovery Time	I _{SD} = 35A, dI _{SD} /dt = 100A/μs	-	-	23	ns
Q _{RR}	Reverse Recovered Charge	I _{SD} = 35A, dI _{SD} /dt = 100A/µs	-	-	9	nC

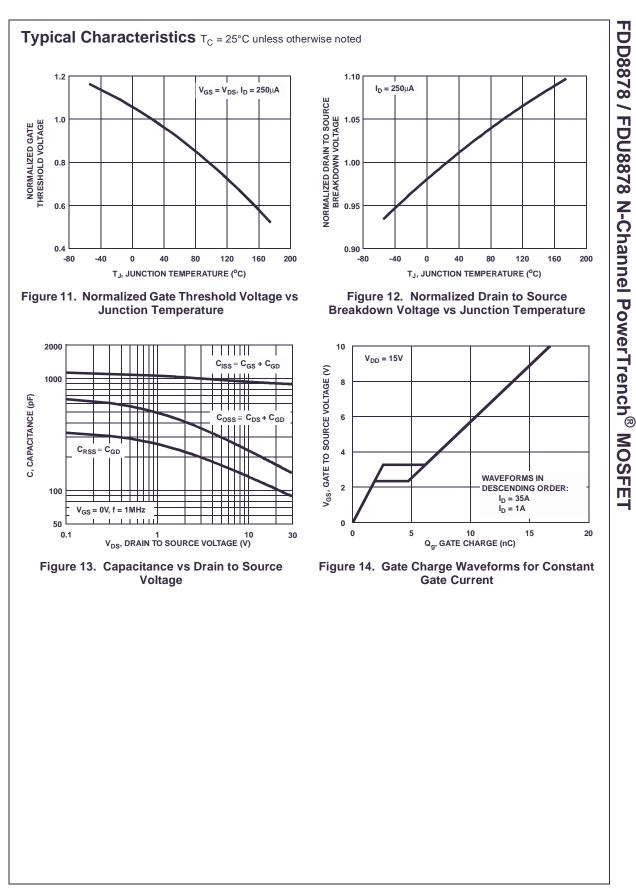
Notes: 1: Package current limitation is 35A. 2: Starting $T_J = 25^{\circ}C$, L = 65uH, I_{AS} = 28A, V_{DD} = 27V, V_{GS} = 10V.

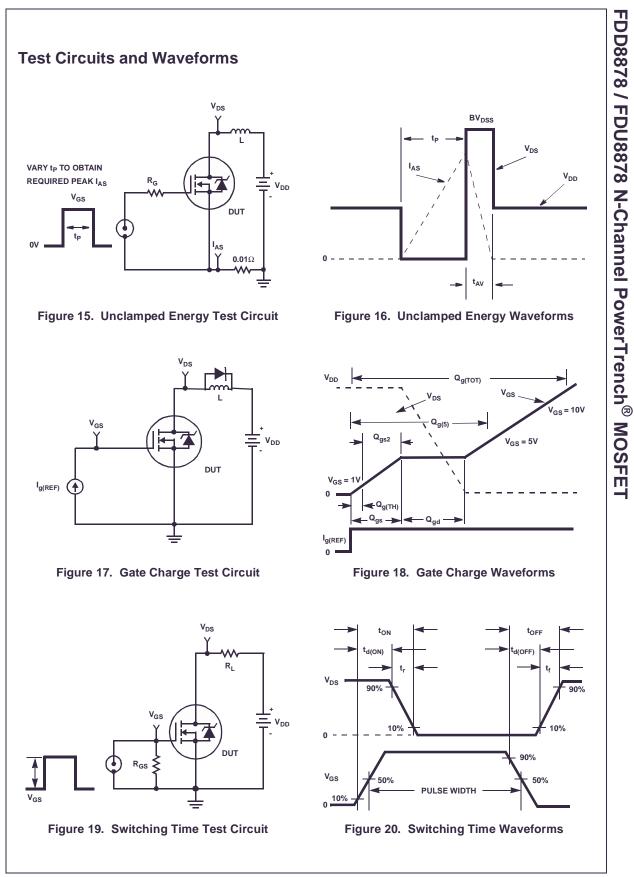


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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta,JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

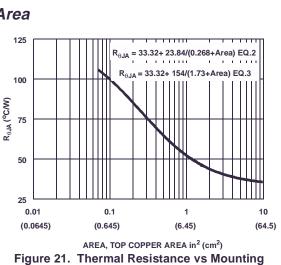
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\theta JA} = 33.32 + \frac{23.84}{(0.268 + Area)}$$
(EQ. 2)

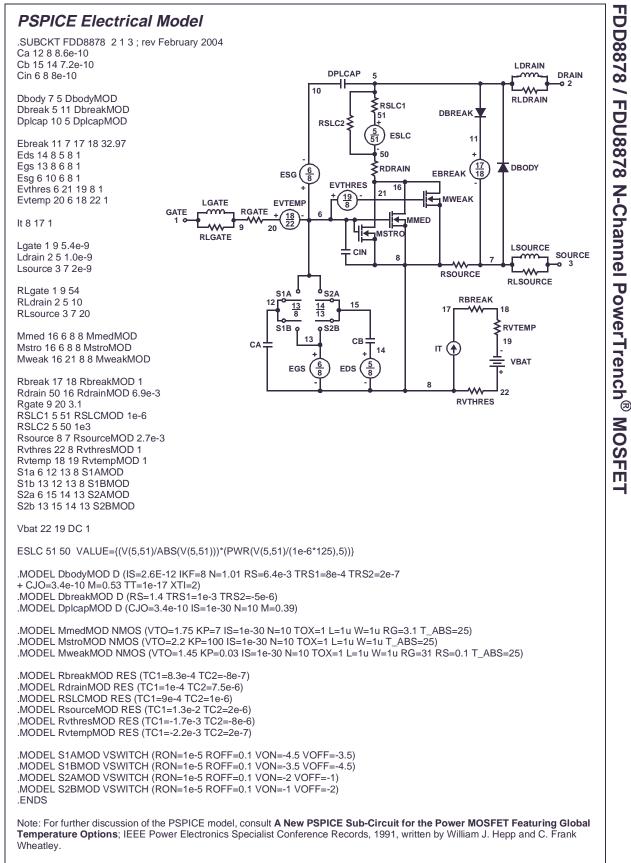
Area in Inches Squared

$$R_{\Theta JA} = 33.32 + \frac{154}{(1.73 + Area)}$$
(EQ. 3)

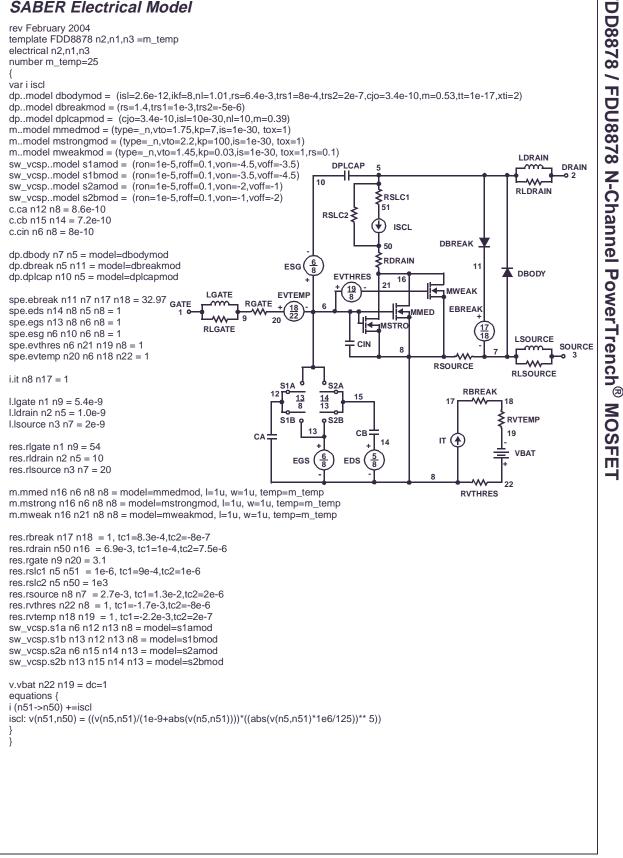
Area in Centimeters Squared

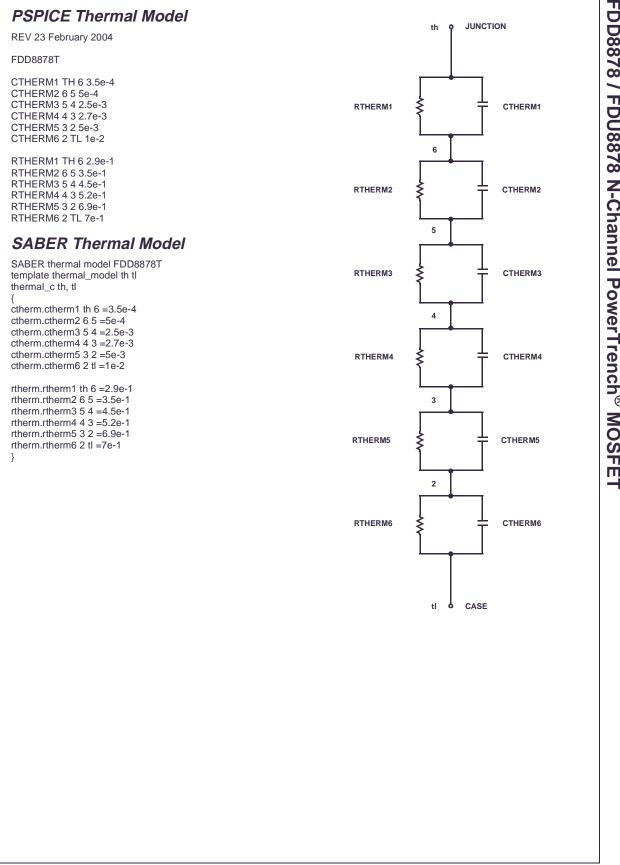


Pad Area



SABER Electrical Model





FDD8878 / FDU8878 N-Channel PowerTrench[®] MOSFET

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